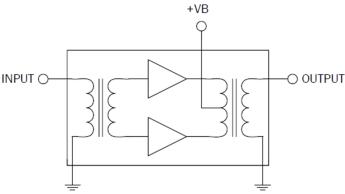


D8740320GT

GaAs Power Doubler Hybrid 40MHz to 870MHz

The D8740320GT is a Hybrid Power Doubler amplifier module. The part employs GaAs die and is operated from 40MHz to 870MHz. It provides excellent linearity and superior return loss performance with low noise and optimal reliability.





Ordering Information

D8740320GT Box with 50 pieces

Absolute Maximum Ratings

Parameter	Rating	Unit
RF Input Voltage (single tone)	75	dBmV
DC Supply Over-Voltage (5 minutes)	30	V
Storage Temperature	-40 to +100	°C
Operating Mounting Base Temperature	-30 to +100	°C



Package: SOT-115J

Features

- Excellent Linearity
- Superior Return Loss Performance
- Extremely Low Distortion
- Optimal Reliability
- Low Noise
- Unconditionally Stable Under All Terminations
- 32.0dB Min. Gain at 870MHz
- 375mA Max. at 24VDC

Applications

 40MHz to 870MHz CATV Amplifier Systems



Caution! ESD sensitive device.



RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2011/65/EU.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implie

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Nominal Operating Parameters

Davamatan	Specification		Ho!t	0 100		
Parameter	eter Min Typ Max Unit Condition		Condition			
General Performance					$V+ = 24V; T_{MB} = 30^{\circ}C; Z_{S} = Z_{L} = 75\Omega$	
Power Gain	30.8		31.5	dB	f = 50MHz	
	32.0		33.5	dB	f = 870MHz	
Slope ^[1]	1.0		2.5	dB	f = 40MHz to 870MHz	
Flatness of Frequency Response			0.6	dB	f = 40MHz to 870MHz (Peak to Valley)	
	20.0			dB	f = 40MHz to 320MHz	
Input Return Loss	19.0			dB	f = 320MHz to 640MHz	
	17.0			dB	f = 640MHz to 870MHz	
	20.0			dB	f = 40MHz to 320MHz	
Output Return Loss	19.0			dB	f = 320MHz to 640MHz	
	18.0			dB	f = 640MHz to 870MHz	
Noise Figure		3.5	4.5	dB	f = 50MHz to 870MHz	
Total Current Consumption (DC)		360.0	375.0	mA		
Distortion Data 40MHz to 750MHz					$V+ = 24V; T_{MB} = 30^{\circ}C; Z_{S} = Z_{L} = 75\Omega$	
СТВ			-60	dBc	112 ch. 10dB tilted; $V_0 = 50 dBmV$ at $750 MHz^{[2]}$	
XMOD			-55	dBc		
cso			-63	dBc		

^{1.} The slope is defined as the difference between the gain at the start frequency and the gain at the stop frequency.

Composite Triple Beat (CTB) - The CTB parameter is defined by the NCTA.

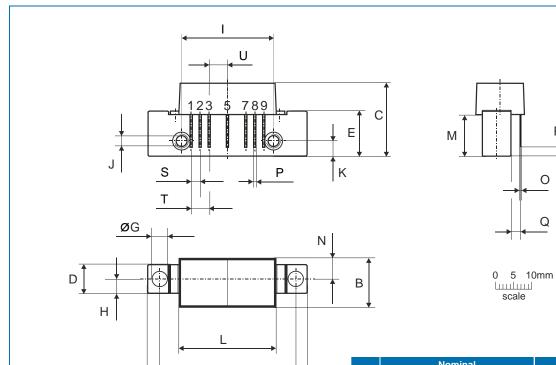
Cross Modulation (XMOD) - Cross modulation (XMOD) is measured at baseband (selective voltmeter method), referenced to 100% modulation of the carrier being tested.

 $^{2.\ 112\} channels,\ NTSC\ frequency\ raster:\ 55.25 MHz\ to\ 745.25 MHz,\ +40 dBmV\ to\ +50 dBmV\ tilted\ output\ level.$ Composite Second Order (CSO) - The CSO parameter (both sum and difference products) is defined by the NCTA.



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Package Drawing (Dimensions in millimeters)



Notes:

European Projection





Pin	Name
1	Input
2-3	GND
4	
5	+VB
6	
7-8	GND
9	Output

	Nominal	Min	Max
Α	44,6 ^{± 0,2}	44,4	44,8
В	13,6 ^{± 0,2}	13,4	13,8
С	20,4 ^{± 0,5}	19,9	20,9
D	8 ^{± 0,15}	7,85	8,15
Е	12,6 ^{± 0,15}	12,45	12,75
F	38,1 ^{± 0,2}	37,9	38,3
G	4 +0,2 / -0,05	3,95	4,2
Н	4 ^{± 0,2}	3,8	4,2
1	25,4 ^{± 0,2}	25,2	25,6
J	UNC 6-32	-	-
K	4,2 ± 0,2	4,0	4,4
L	27,2 ^{± 0,2}	27,0	27,4
М	11,6 ^{± 0,5}	11,1	12,1
N	5,8 ^{± 0,4}	5,4	6,2
0	0,25 ^{± 0,02}	0,23	0,27
Р	0,45 ^{± 0,03}	0,42	0,48
Q	2,54 ^{± 0,3}	2,24	2,84
R	2,54 ^{± 0,5}	2,04	3,04
S	2,54 ^{± 0,25}	2,29	2,79
Т	5,08 ^{± 0,25}	4,83	5,33
U	5,08 ^{± 0,25}	4,83	5,33